



## DESCRIPTION

The D882 is available in SOT-89 Package

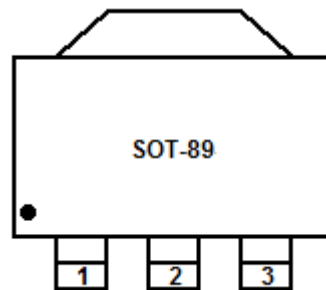
## FEATURES

- Power dissipation
- Available in SOT-89 Package

## ORDERING INFORMATION

Package Type	Part Number
SOT-89	D882
Note	SPQ: 1,000pcs/Reel
AiT provides all RoHS Compliant Products	

## PIN DESCRIPTION



1. BASE
2. COLLECTOR
3. EMITTER



## ABSOLUTE MAXIMUM RATINGS

T<sub>A</sub>=25°C, unless otherwise noted

V <sub>CBO</sub> , Collector-Base Voltage	40V
V <sub>CEO</sub> , Collector-Emitter Voltage	30V
V <sub>EBO</sub> , Emitter-Base Voltage	6V
I <sub>C</sub> , Collector Current-Continuous	1.5A
P <sub>C</sub> , Collector Power Dissipation	1.2W
T <sub>J</sub> , Junction Temperature	150°C
T <sub>STG</sub> , Storage Temperature	-55°C ~150°C

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## ELECTRICAL CHARACTERISTICS

T<sub>amb</sub>=25°C, unless otherwise noted

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> =100μA, I <sub>E</sub> =0	40			V
Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> =10mA, I <sub>B</sub> =0	30			V
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =100μA, I <sub>C</sub> =0	6			V
Collector Cut-off Current	I <sub>CBO</sub>	V <sub>CB</sub> =40V, I <sub>E</sub> =0			1	μA
Collector Cut-off Current	I <sub>CEO</sub>	V <sub>CE</sub> =30V, I <sub>B</sub> =0			10	μA
Emitter Cut-off Current	I <sub>EBO</sub>	V <sub>EB</sub> =6V, I <sub>C</sub> =0			1	μA
DC Current Gain	h <sub>FE(1)</sub>	V <sub>CE</sub> =2V, I <sub>C</sub> =1A	R	60	120	
			O	100	200	
			Y	160	320	
			GR	200	400	
	h <sub>FE(2)</sub>	V <sub>CE</sub> =2V, I <sub>C</sub> =100mA	32			
Collector- Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =2A, I <sub>B</sub> =0.2A			0.5	V
Base-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =2A, I <sub>B</sub> =0.2A			1.5	V
Transition Frequency	f <sub>T</sub>	V <sub>CE</sub> =5V, I <sub>C</sub> =0.1A, f=10MHz	50			MHz



## TYPICAL CHARACTERISTICS

Figure 1. Static Characteristic

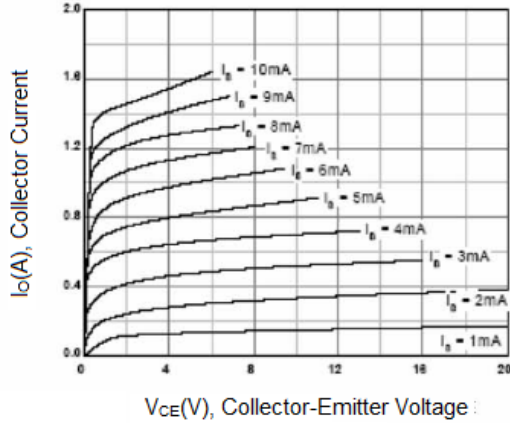


Figure 2. DC Current Gain

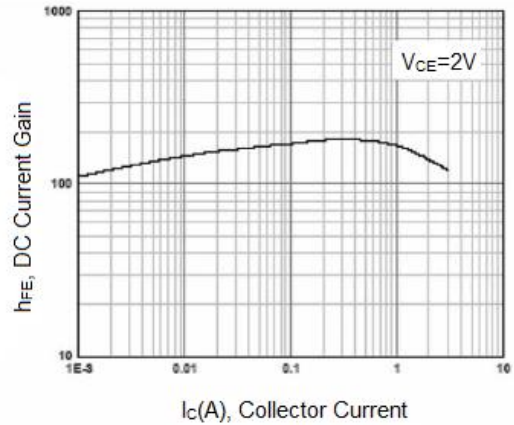


Figure 3. Base-Emitter Saturation Voltage  
Collector-Emitter Saturation Voltage

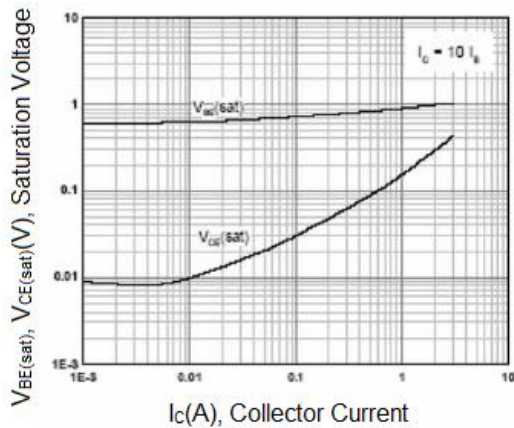


Figure 4. Current Gain Bandwidth Product

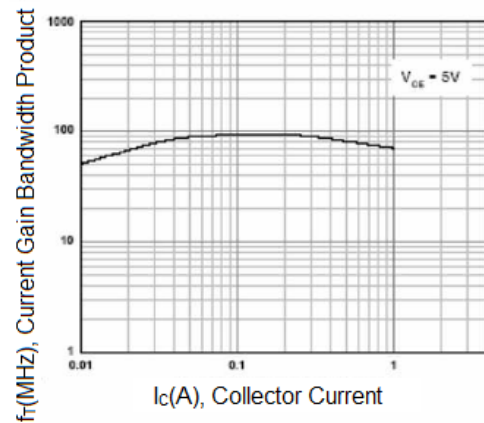
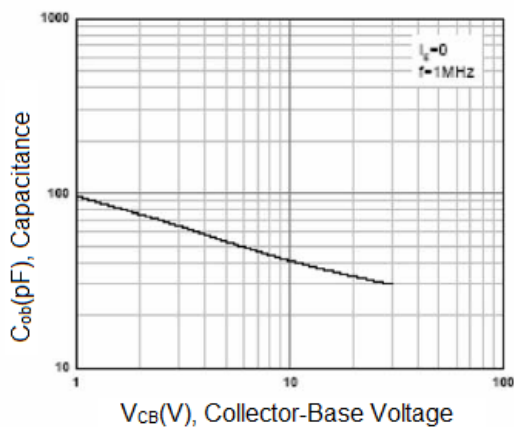


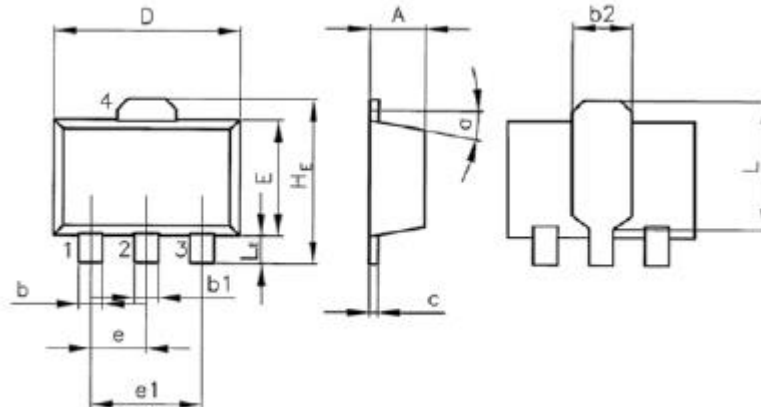
Figure 5. Collector Output Capacitance





## PACKAGE INFORMATION

Dimension in SOT-89 (Unit: mm)



Symbol	Min	Typ	Max
A	-	1.500	-
b	-	-	0.650
b1	-	-	0.650
b2		1.600	-
c	0.250	-	-
D	-	4.500	-
E	-	-	2.600
e	-	1.500	-
e1	-	3.000	-
He	-	-	4.250
L	2.600	-	2.950
Le	0.800	-	1.200
$\alpha$	-	-	10°



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